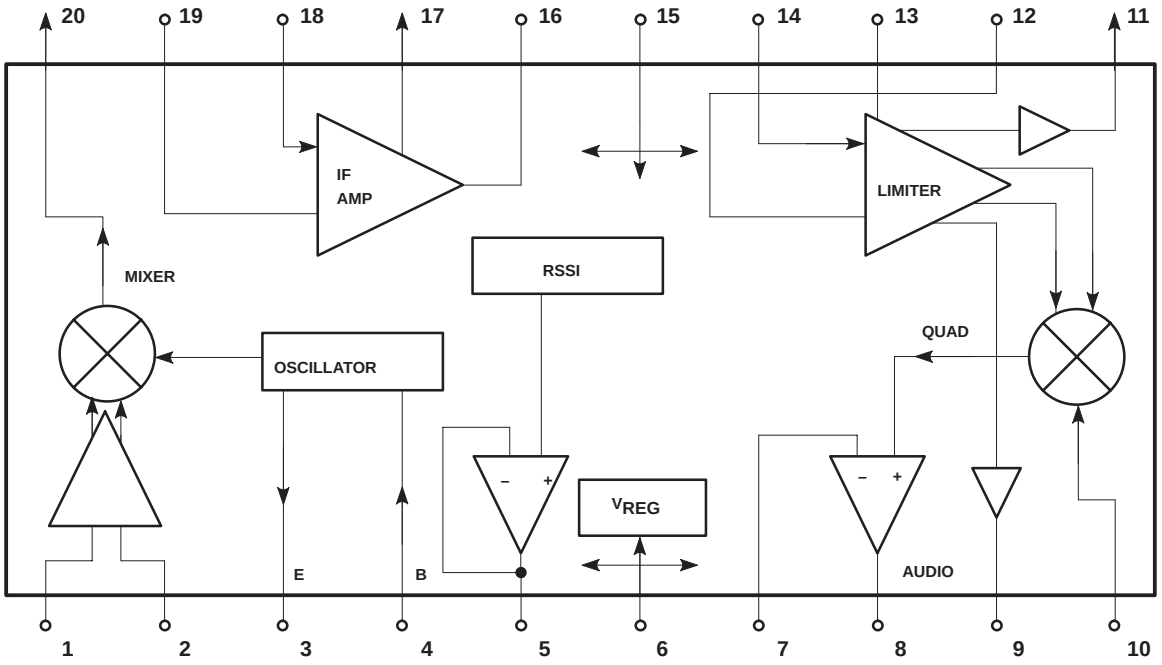
DATA SHEET



SA607

Low-voltage high performance mixer
FM IF system

Product specification
Replaces data of November 3, 1992
IC17 Data Handbook

1997 Nov 07

PHILIPS

Low voltage high performance mixer FM IF system SA607

DESCRIPTION

The SA607 is a low voltage high performance monolithic FM IF system incorporating a mixer/oscillator, two limiting intermediate frequency amplifiers, quadrature detector, logarithmic received signal strength indicator (RSSI), voltage regulator and audio and RSSI op amps. The SA607 is available in 20-lead SOL (surface-mounted miniature package) and 20-lead SSOP package.

The SA607 was designed for portable communication applications and will function down to 2.7V. The RF section is similar to the famous SA605. The audio output has an internal amplifier with the feedback pin accessible. The RSSI output is buffered. The SA607 also has an extra limiter output. This signal is buffered from the output of the limiter and can be used to perform frequency check. This is accomplished by comparing a reference frequency with the frequency check signal using a comparator to a varactor or PLL at the oscillator inputs.

FEATURES

- Low power consumption: 3.5mA typical at 3V
- Mixer input to >150MHz
- Mixer conversion power gain of 17dB at 45MHz
- XTAL oscillator effective to 150MHz (L.C. oscillator or external oscillator can be used at higher frequencies)
- 102dB of IF Amp/Limiter gain
- 2MHz limiter small signal bandwidth
- Temperature compensated logarithmic Received Signal Strength Indicator (RSSI) with a 90dB dynamic range
- Low external component count; suitable for crystal/ceramic/LC filters
- Excellent sensitivity: 0.31µV into 50Ω matching network for 12dB SINAD (Signal to Noise and Distortion ratio) for 1kHz tone, 8kHz deviation with RF at 45MHz and IF at 455kHz
- SA607 meets cellular radio specifications
- Audio output internal op amp
- RSSI output internal op amp

PIN CONFIGURATION

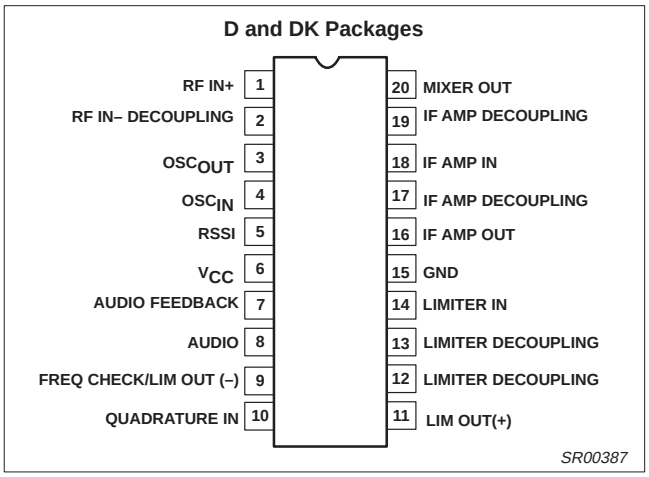


Figure 1. Pin Configuration

- Buffered frequency check output
- Internal op amps with rail-to-rail outputs
- ESD protection: Human Body Model 2kV
  Robot Model 200V

APPLICATIONS

- Portable cellular radio FM IF
- Cordless phones
- Narrow band cellular applications (NAMPS/NTACS)
- RF level meter
- Spectrum analyzer
- Instrumentation
- FSK and ASK data receivers
- Log amps
- Portable high performance communication receivers
- Single conversion VHF receivers
- Wireless systems

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
20-Pin Plastic Small Outline Large (SOL) package (Surface-mount)	-40 to +85°C	SA607D	SOT163-1
20-Pin Plastic Shirnk Small Outline Package (SSOP) (Surface-mount)	-40 to +85°C	SA607DK	SOT266-1

BLOCK DIAGRAM

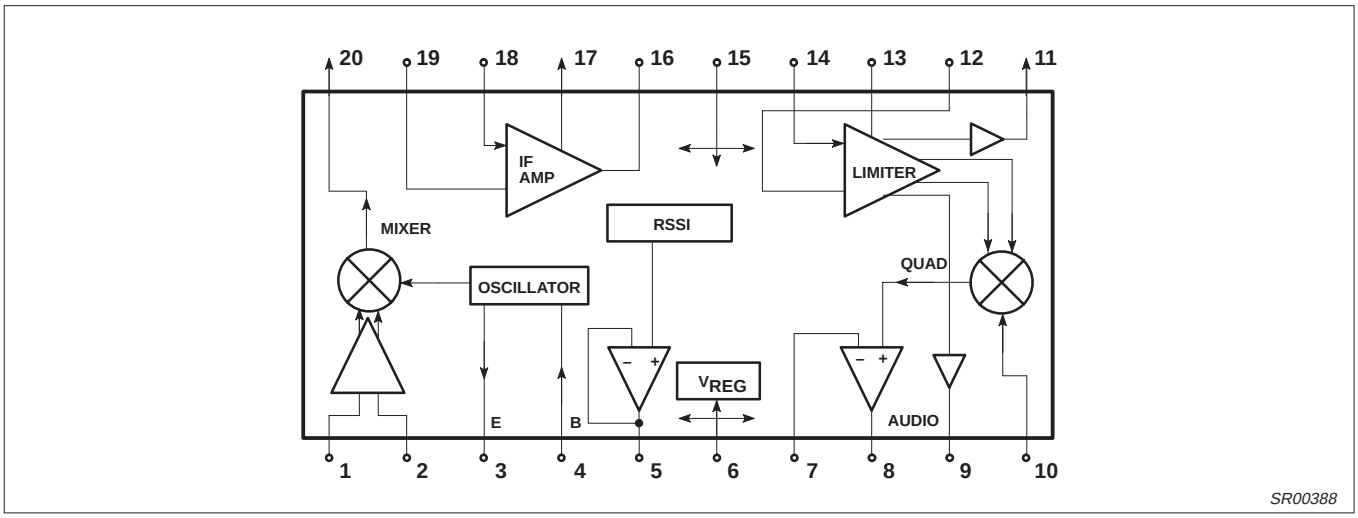


Figure 2. Block Diagram

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V_{CC}	Single supply voltage	7	V
T_{STG}	Storage temperature range	–65 to +150	°C
T_A	Operating ambient temperature range SA607	–40 to +85	°C
θ_{JA}	Thermal impedance D package DK package	90 117	°C/W

DC ELECTRICAL CHARACTERISTICS

V_{CC} = +3V, T_A = 25°C; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			SA607			
			MIN	TYP	MAX	
V_{CC}	Power supply voltage range		2.7		7.0	V
I_{CC}	DC current drain			3.5	4.2	mA

AC ELECTRICAL CHARACTERISTICS

T_A = 25°C; V_{CC} = +3V, unless otherwise stated. RF frequency = 45MHz + 14.5dBV RF input step-up; IF frequency = 455kHz; R17 = 2.4k; R18 = 3.3k; RF level = –45dBm; FM modulation = 1kHz with ±8kHz peak deviation. Audio output with de-emphasis filter and C-message weighted filter. Test circuit 3. The parameters listed below are tested using automatic test equipment to assure consistent electrical characterristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout will improve many of the listed parameters.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			SA607			
			MIN	TYP	MAX	
Mixer/Osc section (ext LO = 220mV$_{RMS}$)						
f_{IN}	Input signal frequency			150		MHz
f_{OSC}	Crystal oscillator frequency			150		MHz
	Noise figure at 45MHz			6.2		dB
	Third–order input intercept point (50Ω source)	f1 = 45.0; f2 = 45.06MHz Input RF Level = –52dBm		–9		dBm
	Conversion power gain	Matched 14.5dBV step–up	13.5	17	19.5	dB
		50Ω source		+2.5		dB
	RF input resistance	Single–ended input		8		kΩ
	RF input capacitance			3.0	4.0	pF
	Mixer output resistance	(Pin 20)	1.25	1.5		kΩ
IF section						
	IF amp gain	50Ω source		44		dB
	Limiter gain	50Ω source		58		dB
	Input limiting –3dB, R_{17} = 2.4k	Test at Pin 18		–109		dBm
	AM rejection	80% AM 1kHz		45		dB
	Audio level	Gain of two (2kΩ AC load)	70	120	160	mV
	SINAD sensitivity	RF level –110dB		17		dB
THD	Total harmonic distortion		–35	–50		dB
S/N	Signal–to–noise ratio	No modulation for noise		62		dB
	IF RSSI output, R_9 = 2kΩ[1]	IF level = –118dBm		0.3	0.8	V
		IF level = –68dBm	.70	1.1	1.80	V
		IF level = –23dBm	1.2	1.8	2.5	V
	RSSI range			90		dB
	RSSI accuracy			±1.5		dB
	IF input impedance		1.3	1.5		kΩ
	IF output impedance			0.3		kΩ
	Limiter input impedance		1.30	1.5		kΩ
	Limiter output impedance	(Pin 11)		200		Ω
	Limiter output level	(Pin 11) No load 5kΩ load		130 115		mV$_{RMS}$
	Frequency check/limiter output impedance	(Pin 9)		200		Ω
	Frequency check/limiter output level	(Pin 9) No load 5kΩ load		130 115		mV$_{RMS}$
RF/IF section (int LO)						
	Audio level	3V = V_{CC}, RF level = –27dBm		120		mV$_{RMS}$
	System RSSI output	3V = V_{CC}, RF level = –27dBm		2.2		V
	System SINAD sensitivity	RF level = –117dBm		12		dB

NOTE:
1. The generator source impedance is 50Ω, but the SA607 input impedance at Pin 18 is 1500Ω. As a result, IF level refers to the actual signal that enters the SA607 input (Pin 18) which is about 21dB less than the “available power” at the generator.

CIRCUIT DESCRIPTION

The SA607 is an IF signal processing system suitable for second IF systems with input frequency as high as 150MHz. The bandwidth of the IF amplifier and limiter is at least 2MHz with 90dB of gain. The gain/bandwidth distribution is optimized for 455kHz, 1.5kΩ source applications. The overall system is well-suited to battery operation as well as high performance and high quality products of all types.

The input stage is a Gilbert cell mixer with oscillator. Typical mixer characteristics include a noise figure of 6.2dB, conversion gain of 17dB, and input third-order intercept of –9dBm. The oscillator will operate in excess of 200MHz in L/C tank configurations. Hartley or Colpitts circuits can be used up to 100MHz for xtal configurations. Butler oscillators are recommended for xtal configurations up to 150MHz.

The output impedance of the mixer is a 1.5kΩ resistor permitting direct connection to a 455kHz ceramic filter. The input resistance of the limiting IF amplifiers is also 1.5kΩ. With most 455kHz ceramic filters and many crystal filters, no impedance matching network is necessary. The IF amplifier has 43dB of gain and 5.5MHz bandwidth. The IF limiter has 60dB of gain and 4.5MHz bandwidth. To achieve optimum linearity of the log signal strength indicator, there must be a 12dB(v) insertion loss between the first and second IF stages. If the IF filter or interstage network does not cause 12dB(v) insertion loss, a fixed or variable resistor or an L pad for simultaneous loss and impedance matching can be added between the first IF output (Pin 16) and the interstage network. The overall gain will then be 90dB with 2MHz bandwidth.

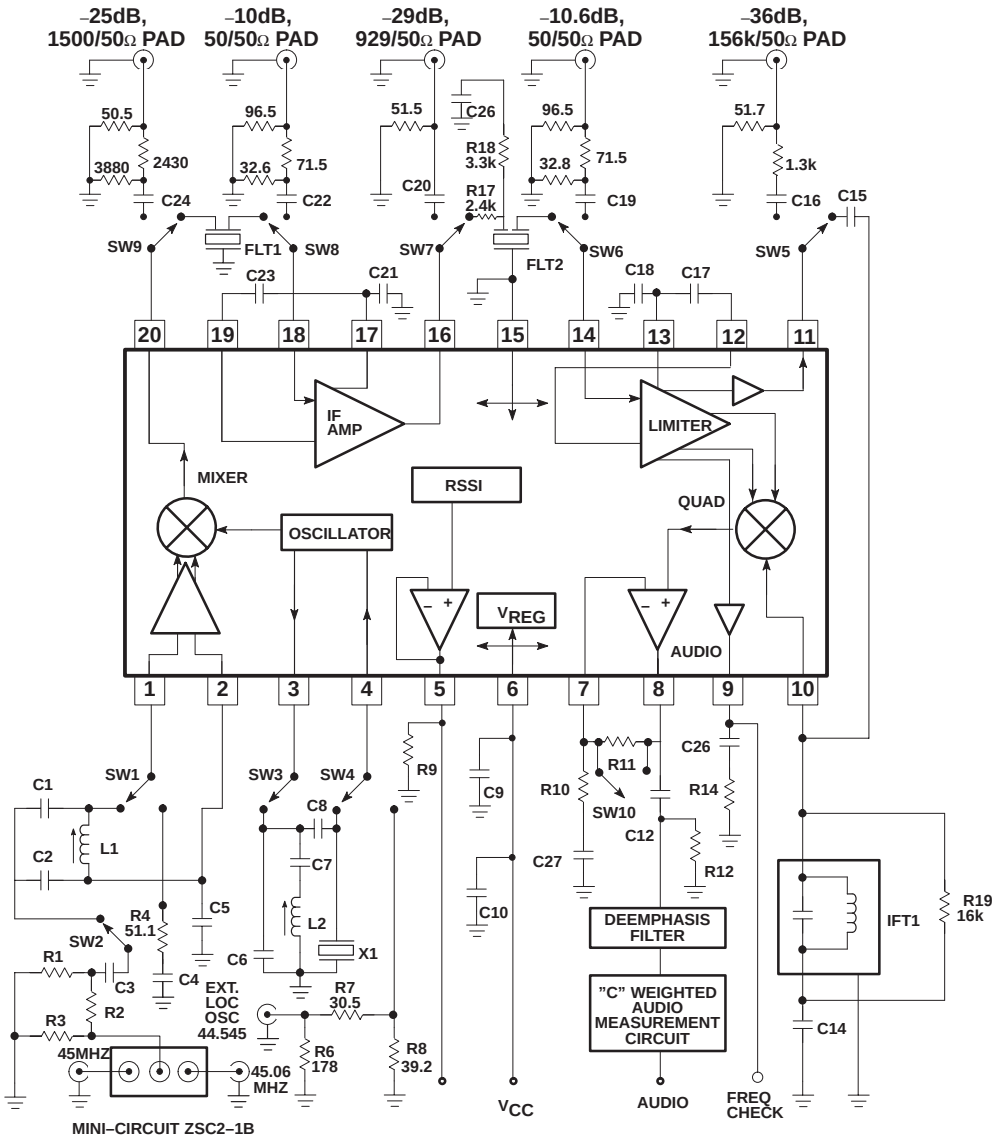
The signal from the second limiting amplifier goes to a Gilbert cell quadrature detector. One port of the Gilbert cell is internally driven by the IF. The other output of the IF is AC-coupled to a tuned quadrature network. This signal, which now has a 90° phase relationship to the internal signal, drives the other port of the multiplier cell.

The demodulated output of the quadrature drives an internal op amp. This op amp can be configured as a unity gain buffer, or for simultaneous gain, filtering, and 2nd-order temperature compensation if needed. It can drive an AC load as low as 5kΩ with a rail-to-rail output.

A log signal strength completes the circuitry. The output range is greater than 90dB and is temperature compensated. This log signal strength indicator exceeds the criteria for AMPs or TACs cellular telephone. This signal is buffered through an internal unity gain op amp. The frequency check pin provides a buffered limiter output. This is useful for implementing an AFC (Automatic Frequency Check) function. This same output can also be used in conjunction with limiter output (Pin 11) for demodulating FSK (Frequency Shift Keying) data. Both pins are of the same amplitude, but 180° out of phase.

NOTE: Limiter output or Frequency Check output has drive capability of a load minimum of 2kΩ or higher to obtain 115mV output level.

NOTE: $dB(v) = 20\log V_{OUT}/V_{IN}$



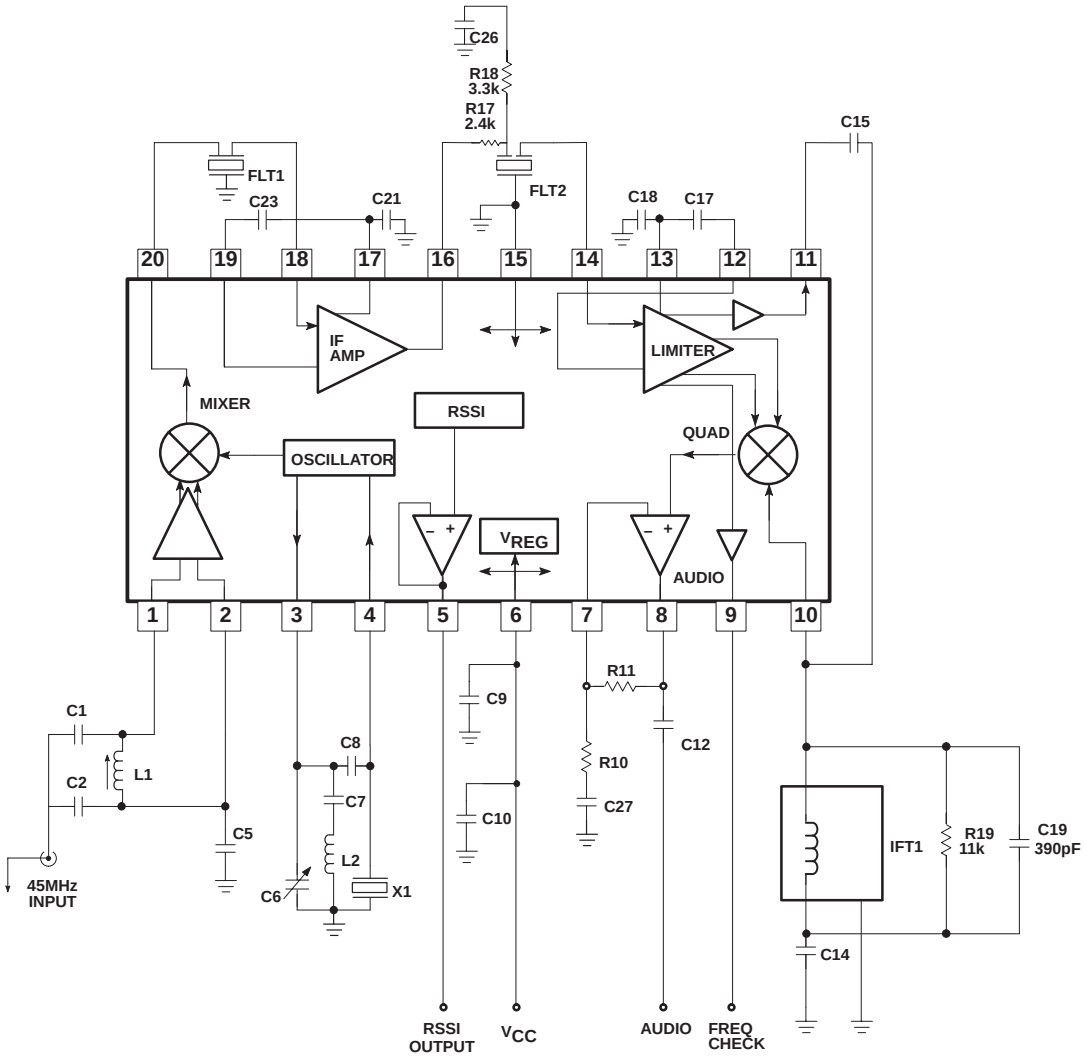
Automatic Test Circuit Component List

C1	100pF NPO Ceramic
C2	390pF NPO Ceramic
C5	100nF ±10% Monolithic Ceramic
C6	22pF NPO Ceramic
C7	1nF Ceramic
C8	10.0pF NPO Ceramic
C9	100nF ±10% Monolithic Ceramic
C10	10μF Tantalum (minimum) *
C12	2.2μF
C14	100nF ±10% Monolithic Ceramic
C15	10pF NPO Ceramic
C17	100nF ±10% Monolithic Ceramic
C18	100nF ±10% Monolithic Ceramic
C21	100nF ±10% Monolithic Ceramic
C23	100nF ±10% Monolithic Ceramic
C25	100nF ±10% Monolithic Ceramic
C26	0.1μF ±10% Monolithic Ceramic
C27	2.2μF
Flt 1	Ceramic Filter Murata SFG455A3 or equiv
Flt 2	Ceramic Filter Murata SFG455A3 or equiv
IFT 1	455kHz (Ce = 180pF) Toko RMC–2A6597H
L1	147–160nH Coilcraft UNI–10/142–04J08S
L2	0.8μH nominal Toko 292CNS–T1038Z
X1	44.545MHz Crystal ICM4712701
R9	2kΩ ±1% 1/4W Metal Film
R10	8.2kΩ ±1%
R11	10kΩ ±1%
R12	2kΩ ±1%
R14	5kΩ ±1%
R17	2.4kΩ ±5% 1/4W Carbon Composition
R18	3.3kΩ ±5% 1/4W Carbon Composition
R19	16kΩ ±5% 1/4W Carbon Composition

***NOTE: This value can be reduced when a battery is the power source.**

SR00389

Figure 3. SA607 45MHz Test Circuit (Relays as shown)



SA607D/DK
Application Component List

C1	51pF NPO Ceramic
C2	220pF NPO Ceramic
C5	100nF ±10% Monolithic Ceramic
C6	5-30pF trim cap
C7	1nF Ceramic
C8	10.0pF NPO Ceramic
C9	100nF ±10% Monolithic Ceramic
C10	10μF Tantalum (minimum) *
C12	2.2μF ±10% Tantalum
C14	100nF ±10% Monolithic Ceramic
C15	10pF NPO Ceramic
C17	100nF ±10% Monolithic Ceramic
C18	100nF ±10% Monolithic Ceramic
C19	390pF ±10% Monolithic Ceramic
C21	100nF ±10% Monolithic Ceramic
C23	100nF ±10% Monolithic Ceramic
C26	100nF ±10% Monolithic Ceramic
C27	2.2μF Tantalum
Flt 1	Ceramic Filter Murata SFG455A3 or equiv
Flt 2	Ceramic Filter Murata SFG455A3 or equiv
IFT 1	330μH TOKO 303LN-1130
L1	.33μH TOKO SCB-1320Z
L2	1.2μH Coilcraft 1008C S-122
X1	44.545MHz Crystal Hy–Q
R5	Not Used in Application Board (see Note 8, pg 8)
R10	8.2k ±5% 1/4W Carbon Composition
R11	10k ±5% 1/4W Carbon Composition
R17	2.4k ±5% 1/4W Carbon Composition
R18	3.3k ±5% 1/4W Carbon Composition
R19	11k ±5% 1/4W Carbon Composition

*NOTE: This value can be reduced when a battery is the power source.

SR00390

Figure 4. SA607 45MHz Application Circuit

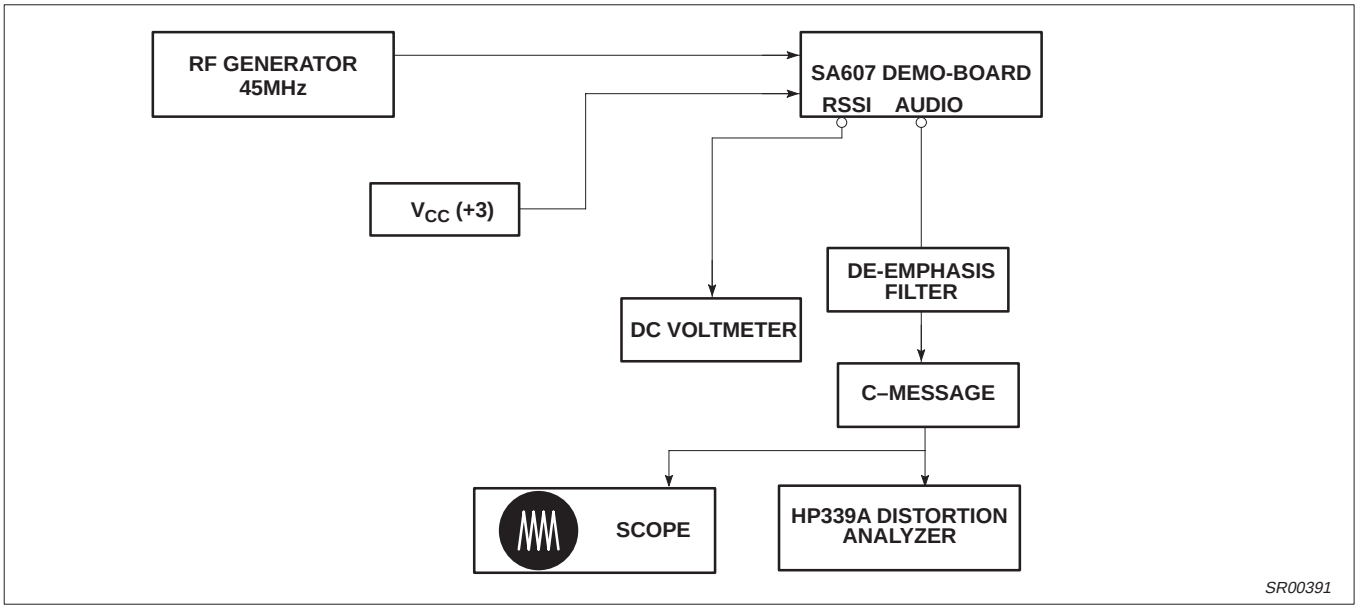


Figure 5. SA607 Application Circuit Test Set Up

NOTES:
1. C-message: The C-message and de-emphasis filter combination has a peak gain of 10 for accurate measurements. Without the gain, the measurements may be affected by the noise of the scope and HP339 analyzer. The de-emphasis filter has a fixed -6dB/Octave slope between 300Hz and 3kHz.
2. Ceramic filters: The ceramic filters can be 30kHz SFG455A3s made by Murata which have 30kHz IF bandwidth (they come in blue), or 16kHz CFU455Ds, also made by Murata (they come in black). All of our specifications and testing are done with the more wideband filter.
3. RF generator: Set your RF generator at 45.000MHz, use a 1kHz modulation frequency and a 6kHz deviation if you use 16kHz filters, or 8kHz if you use 30kHz filters.
4. Sensitivity: The measured typical sensitivity for 12dB SINAD should be 0.35μV or –116dBm at the RF input.
5. Layout: The layout is very critical in the performance of the receiver. We highly recommend our demo board layout.
6. RSSI: The smallest RSSI voltage (i.e., when no RF input is present and the input is terminated) is a measure of the quality of the layout and design. If the lowest RSSI voltage is 500mV or higher, it means the receiver is in regenerative mode. In that case, the receiver sensitivity will be worse than expected.
7. Supply bypass and shielding: All of the inductors, the quad tank, and their shield must be grounded. A 10-15μF or higher value tantalum capacitor on the supply line is essential. A low frequency ESR screening test on this capacitor will ensure consistent good sensitivity in production. A 0.1μF bypass capacitor on the supply pin, and grounded near the 44.545MHz oscillator improves sensitivity by 2-3dB.
8. R5 can be used to bias the oscillator transistor at a higher current for operation above 45MHz. Recommended value is 22kΩ, but should not be below 10kΩ.

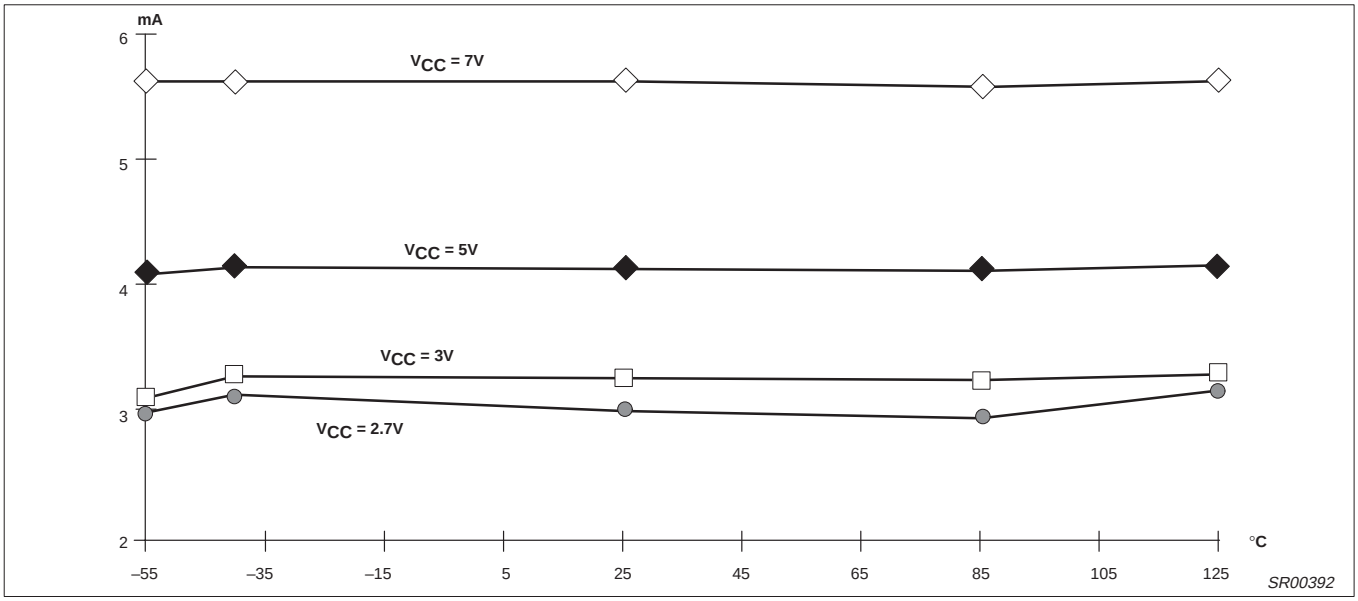


Figure 6. I_{CC} vs Temperature

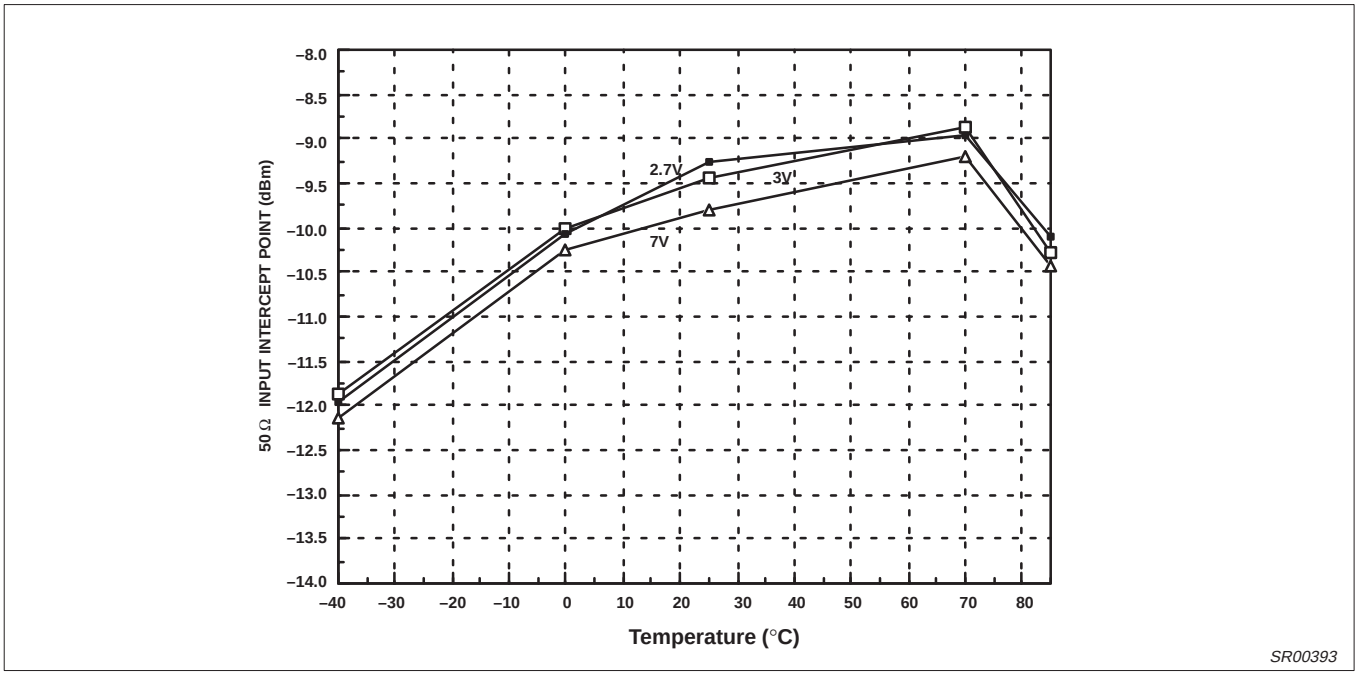


Figure 7. Third Order Intercept Point vs Supply Voltage

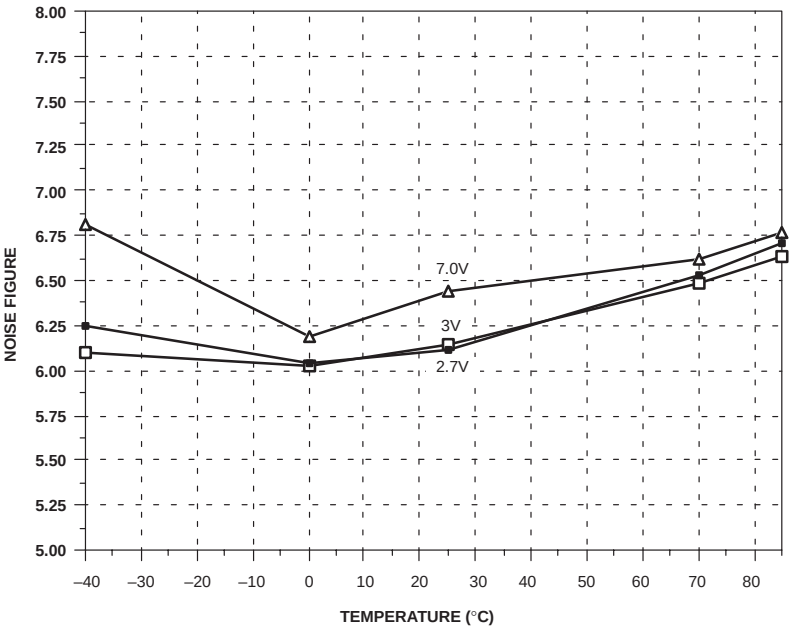


Figure 8. Mixer Noise Figure vs Supply Voltage

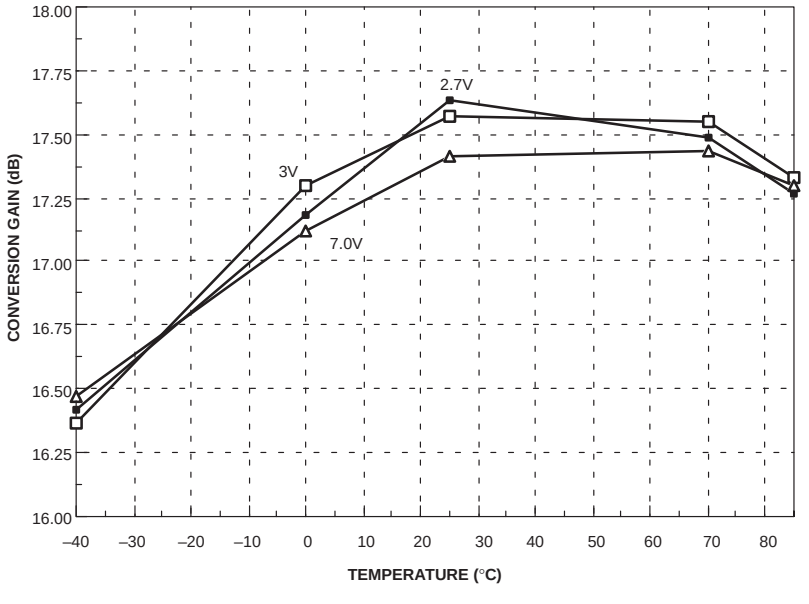


Figure 9. Conversion Gain vs Supply Voltage

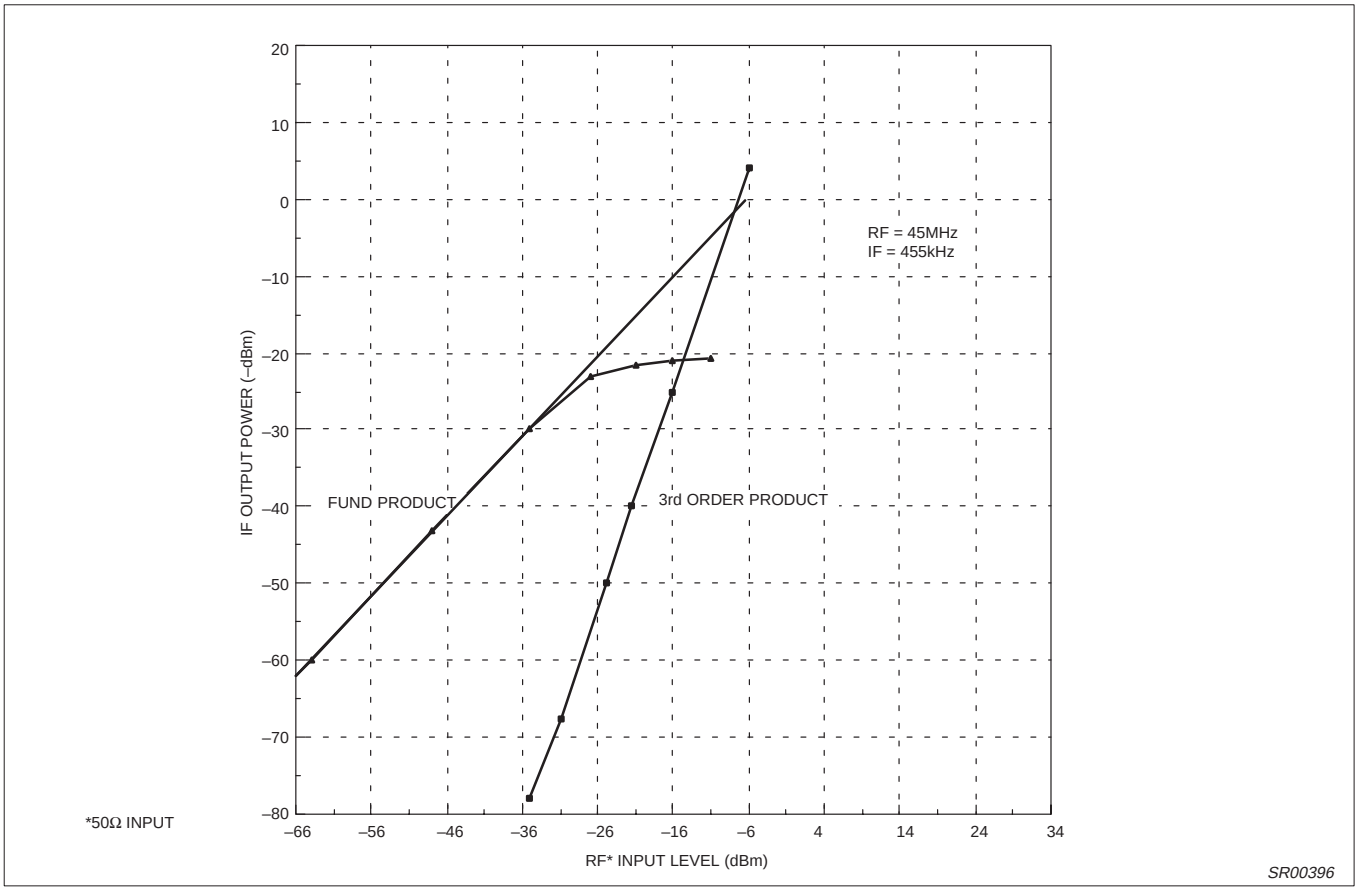


Figure 10. Mixer Third Order Intercept and Compression

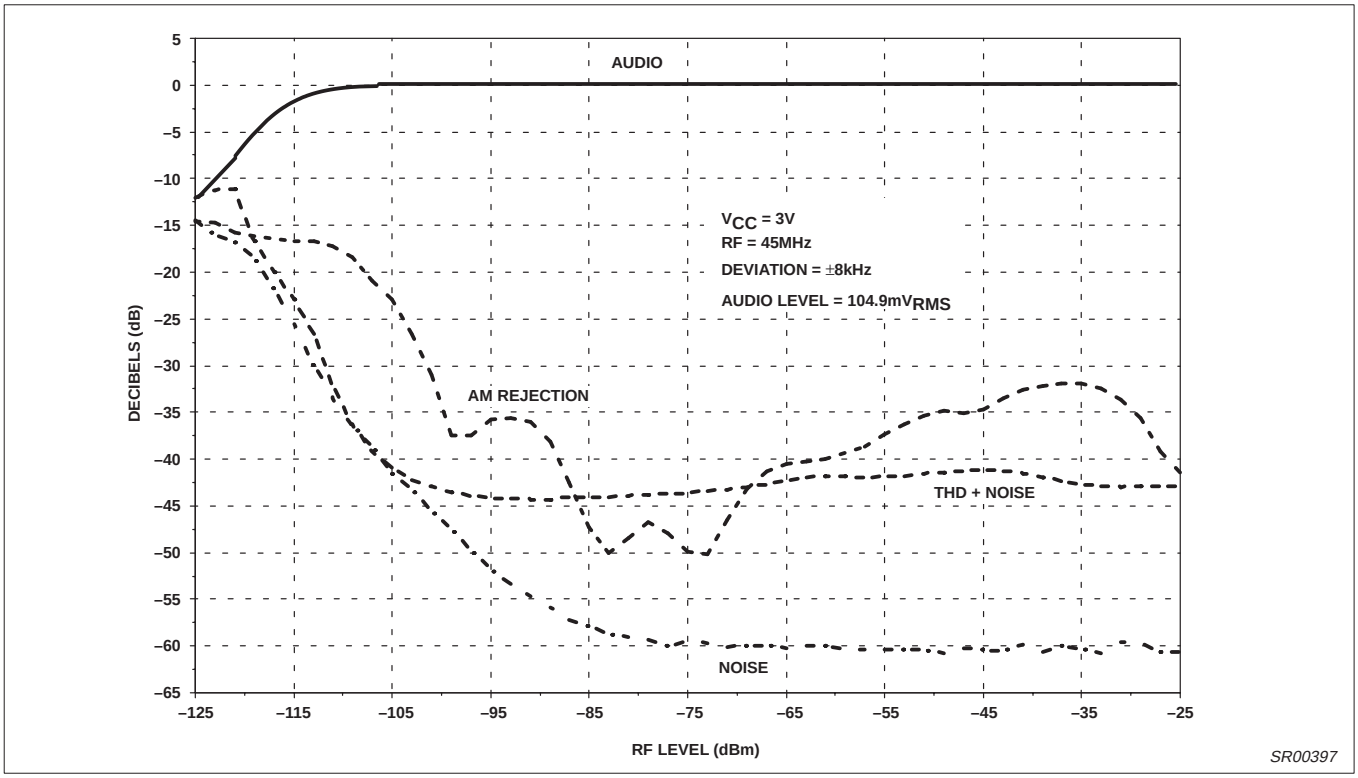


Figure 11. Sensitivity vs RF Level (–40°C)

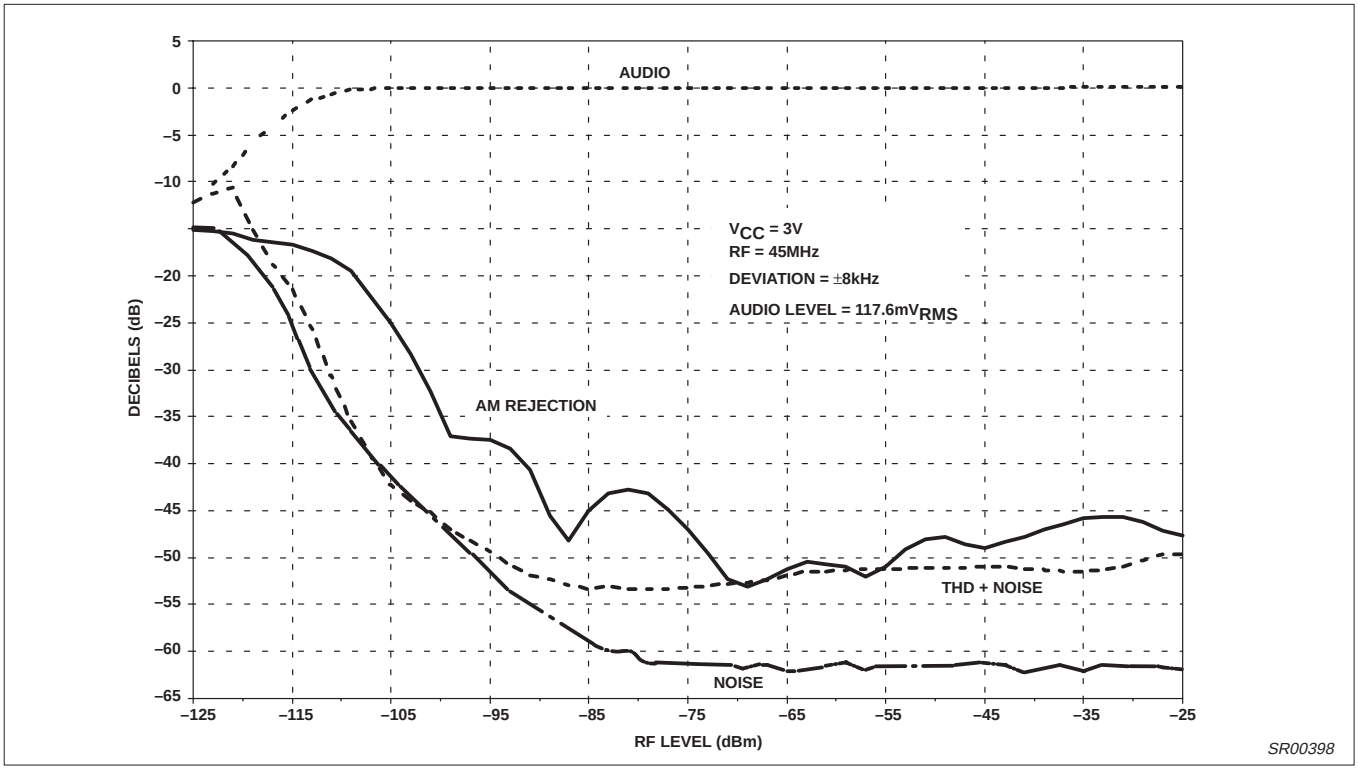


Figure 12. Sensitivity vs RF Level (+25°C)

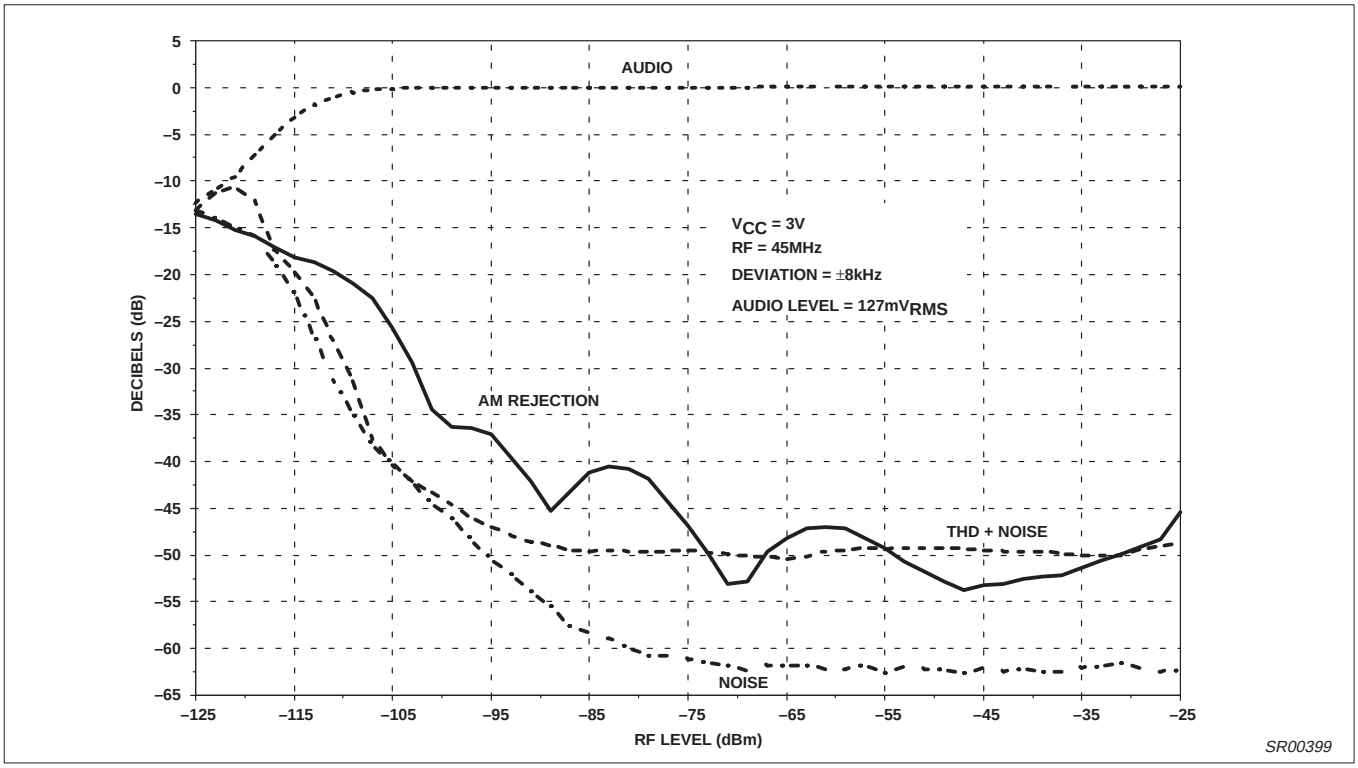


Figure 13. Sensitivity vs RF Level (Temperature 85°C)

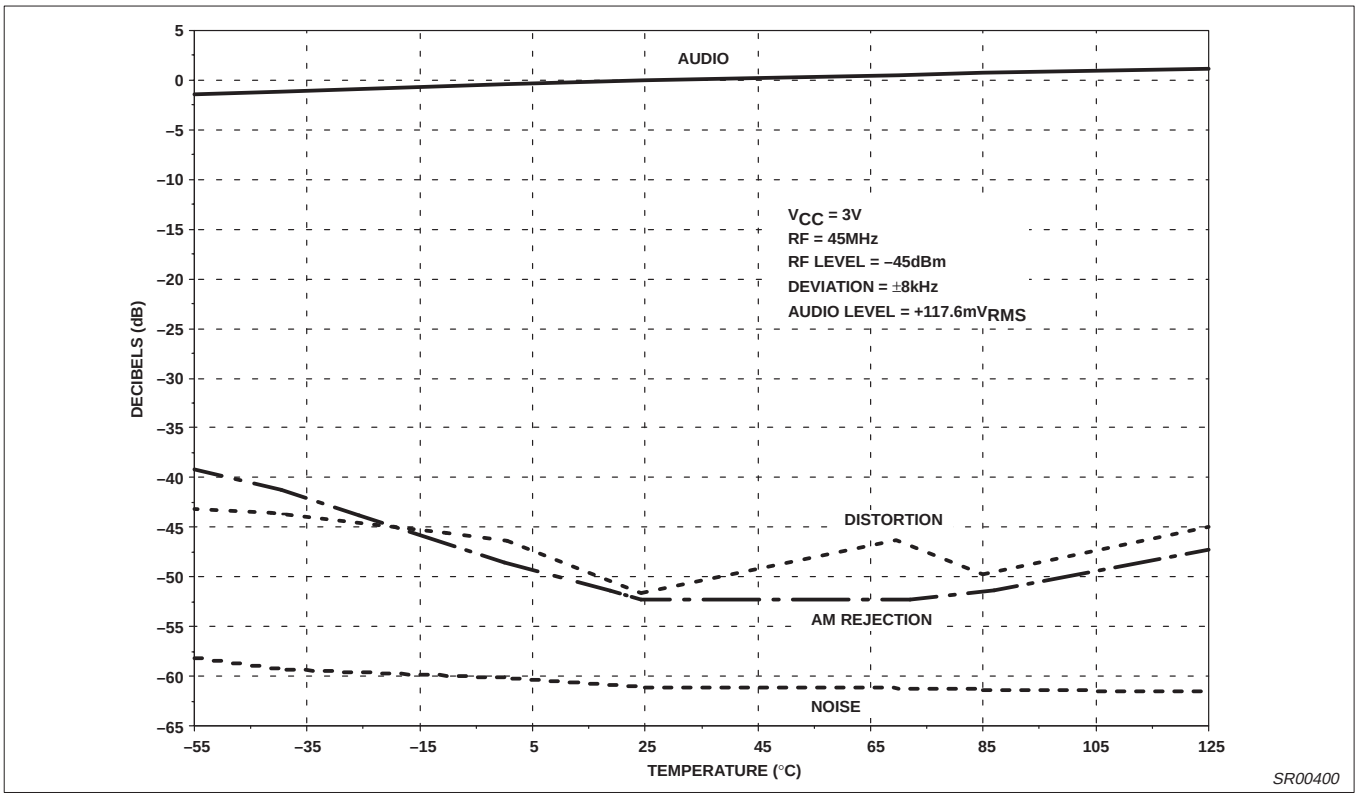


Figure 14. Relative Audio Level, Distortion, AM Rejection and Noise vs Temperature

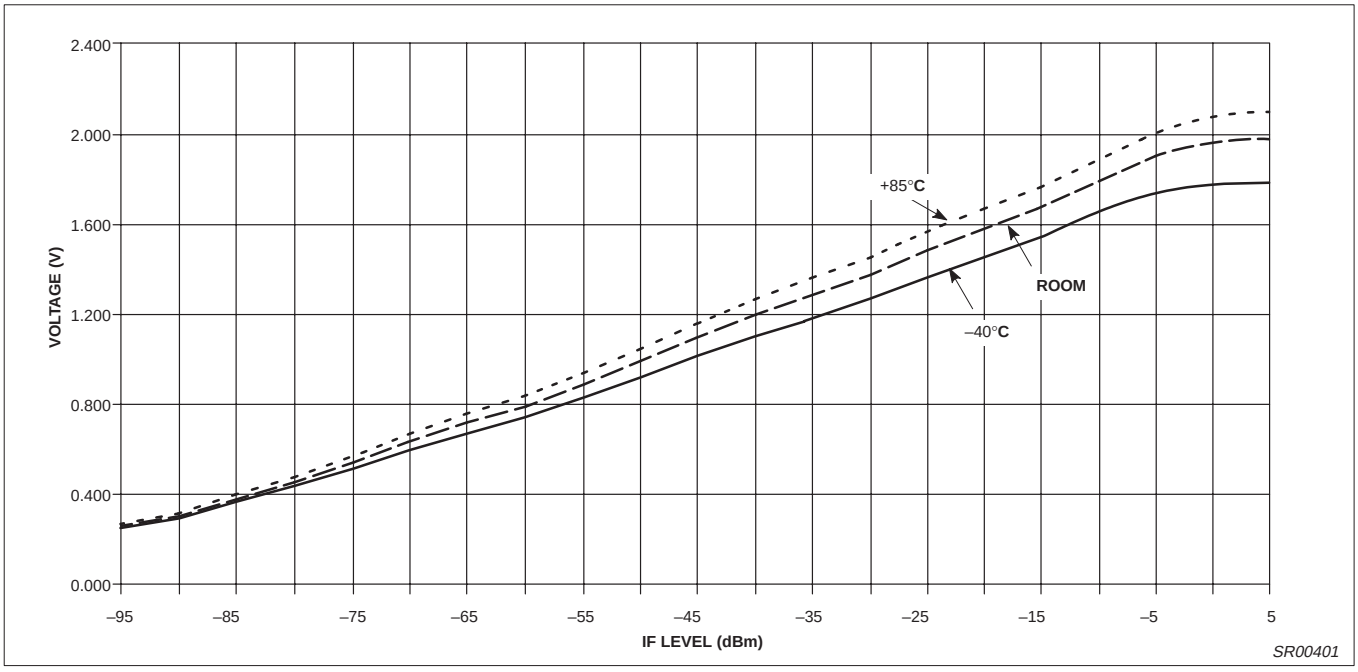


Figure 15. RSSI (455kHz IF @ 3V)

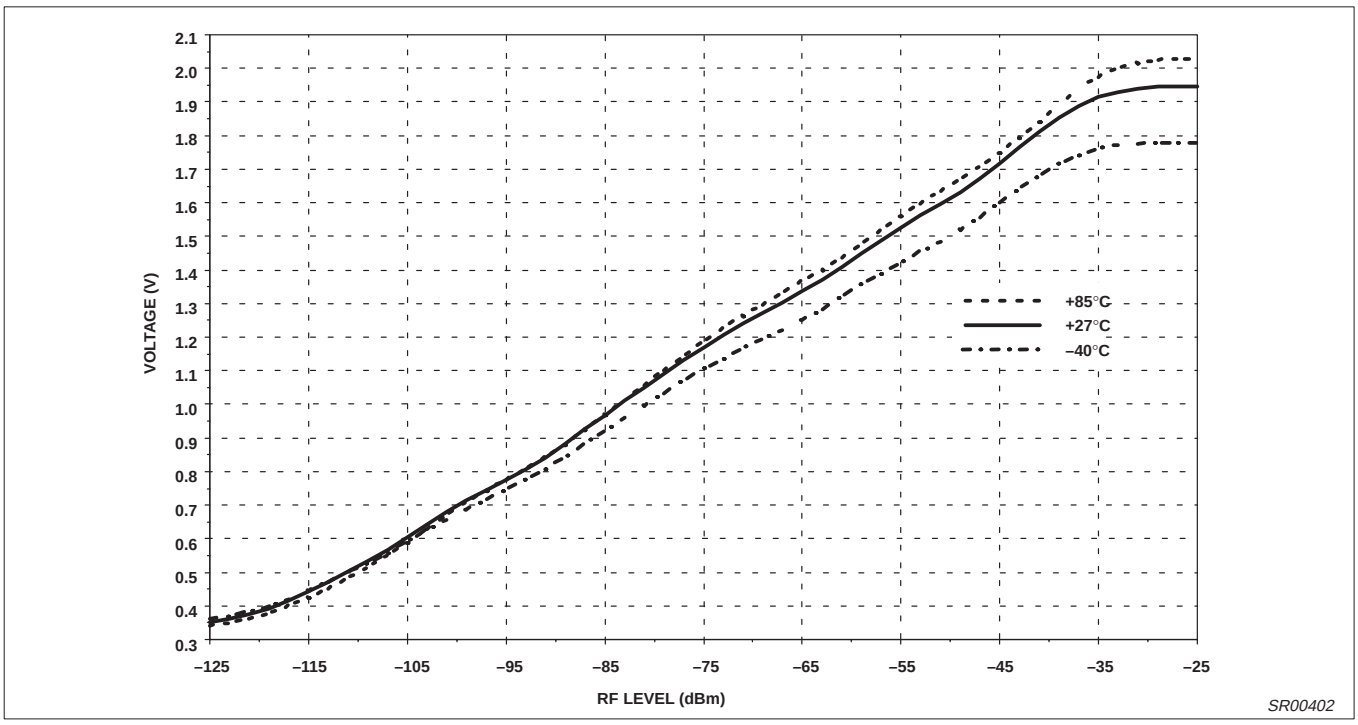


Figure 16. RSSI vs RF Level and Temperature - V_{CC} = 3V

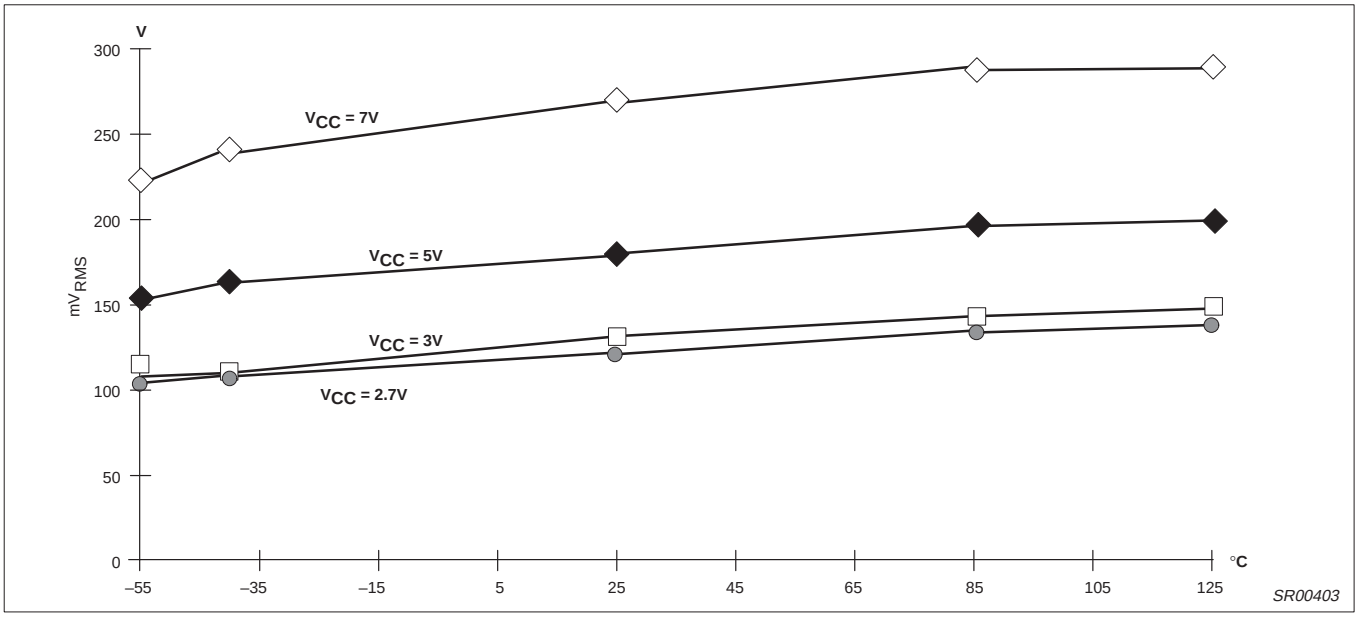
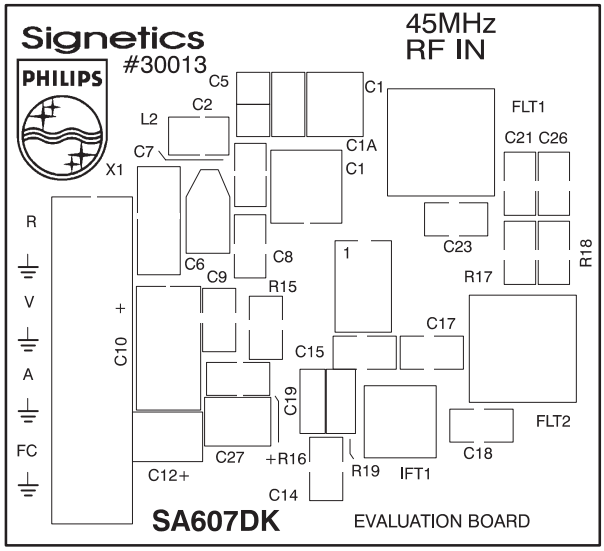
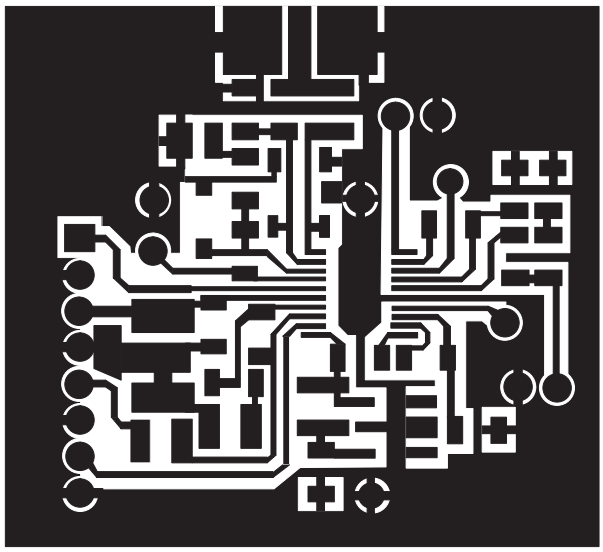


Figure 17. Audio Output vs Temperature

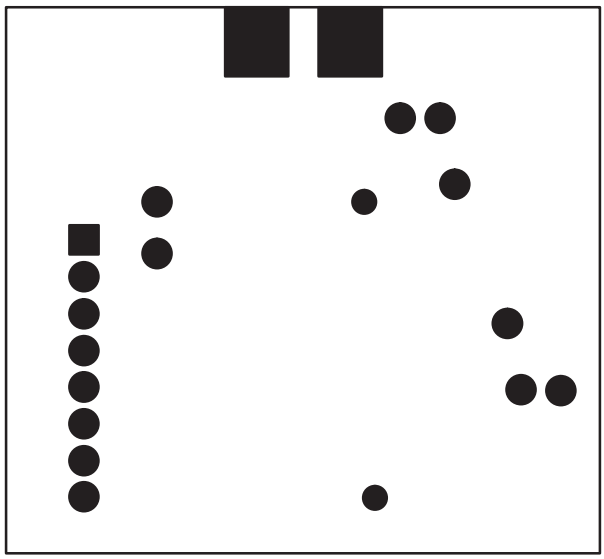
607 Silk Screen



607 TOP



607 BOTTOM

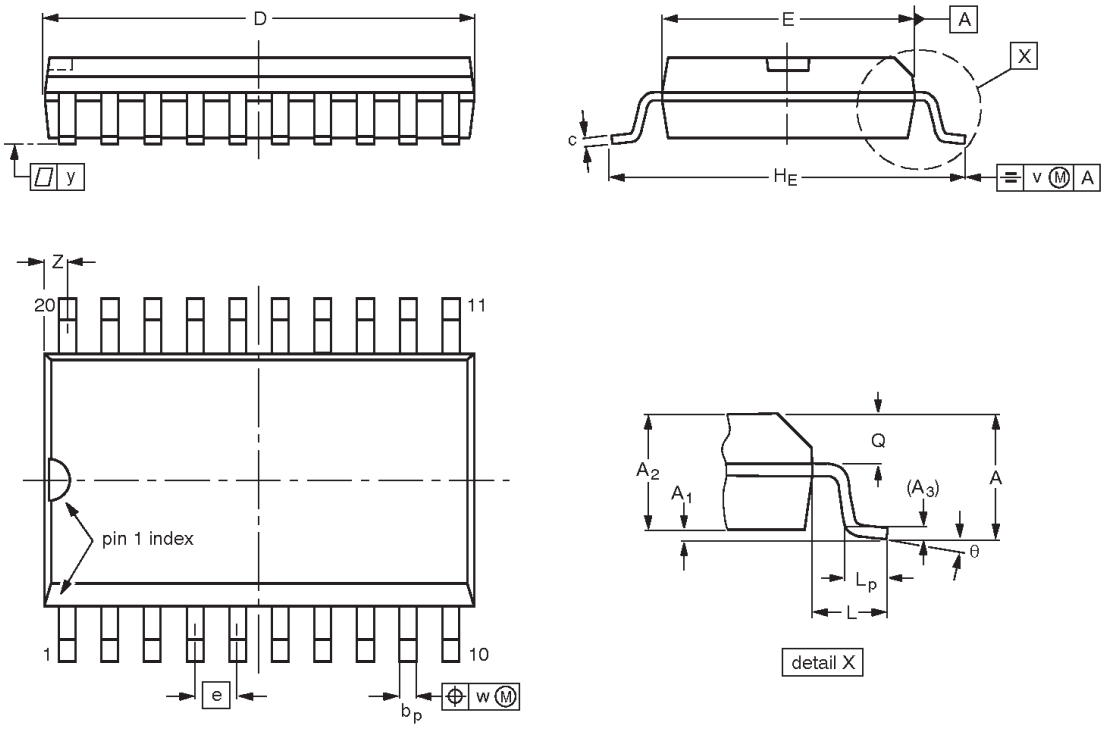


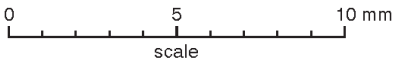
NOTE;
All views are TOP VIEW and not actual size. For reference only.

SR00404

Figure 18.

SO20: plastic small outline package; 20 leads; body width 7.5 mm SOT163-1





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

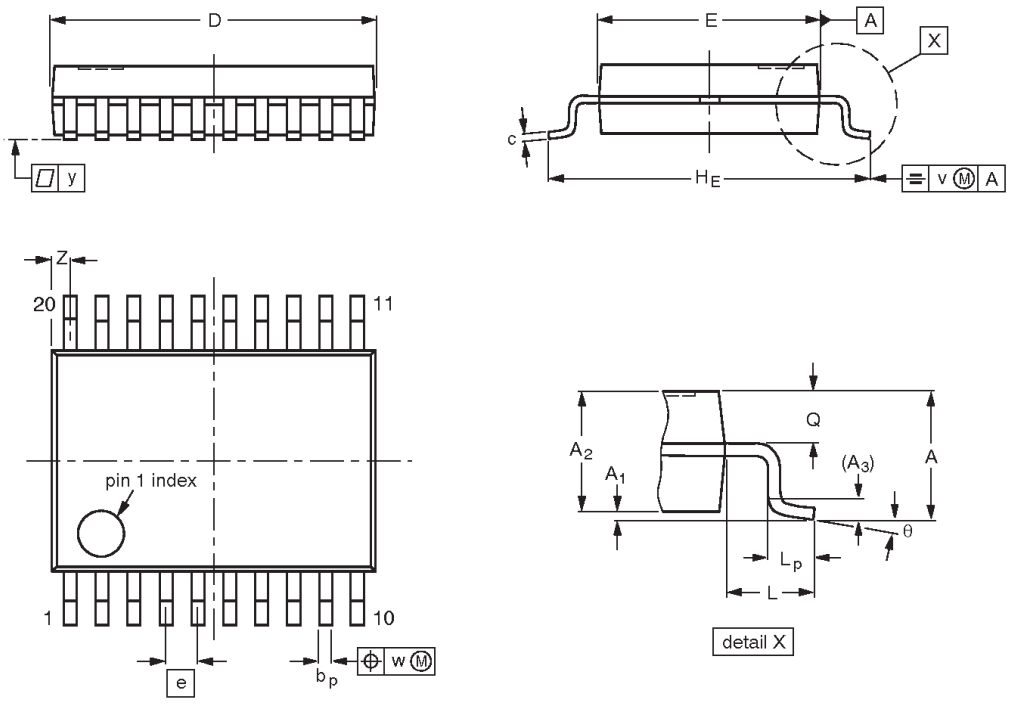
UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (1)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8^o 0^o
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

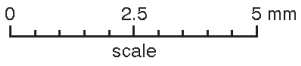
Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT163-1	075E04	MS-013AC				~~92-11-17~~ 95-01-24

SSOP20: plastic shrink small outline package; 20 leads; body width 4.4 mm **SOT266-1**





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.5	0.15 0	1.4 1.2	0.25	0.32 0.20	0.20 0.13	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.45	0.65 0.45	0.2	0.13	0.1	0.48 0.18	10^o 0^o

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES					EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ				
SOT266-1							~~90-04-05~~ 95-02-25

DEFINITIONS

Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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